PNP Epitaxial Planar Silicon Transistor



2SA1857

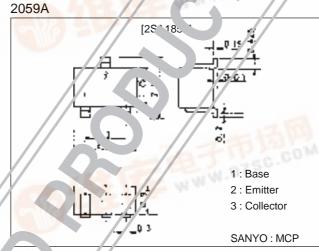
# FM, RF, MIX, IF Amplifier High-Frequency General-Purpose Amplifier Applications

## **Features**

- · High power gain : PG=25dB typ (f=100MHz).
- · High cutoff frequency : f<sub>T</sub>=750MHz typ.
- · Low collector-to-emitter saturation voltage.
- · Complementary pair with the 2SC4400.

## Package Dimensions

unit:mm



# **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CPO</sub>		-15	V
Collector-to-Emitter Voltage	VCEO		-12	V
Emitter-to-Base Voltage	V <sub>E</sub> BO		-3	V
Collector Current	//I <sub>C</sub>		-50	mA
Collector Dissipation	PC		150	mW
Junction Temperature	Ti Ti		150	°C
Storage Temperature	sty		-55 to +150	°C

## Electrical Characteristics at Ta = 2

Parameter	`'mbol	Conditions	Ratings			Unit
Falametel			min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CI3</sub> =-12V, I <sub>E</sub> =0			-0.1	μΑ
Emitter Cutoff Current	EBO	V <sub>EB</sub> =-2V, I <sub>C</sub> =0			-0.1	μΑ
DC Current Gain	hFE	V <sub>CE</sub> =-10V, I <sub>C</sub> =-5mA	60*		270*	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =-10V, I <sub>C</sub> =-5mA		750	1	MHz
Output Capacitance	Sols	V <sub>CB</sub> =-10V, f=1MHz		1.2	1.6	pF
Reverse Transfer Caspacitance	Cre	V <sub>CB</sub> =-10V, f=1MHz		0.9	20.	pF
Collector-to-Emitter Sature on Voltage	VCE(sat)	I <sub>C</sub> =-10mA, I <sub>B</sub> =-1mA	W W	-0.1	-0.3	V
Power Gain	PG	V <sub>CE</sub> =-10V, I <sub>C</sub> =-10mA, f=100MHz		25		dB

\*: The 2S A1'357 is class ind by A here as follows:

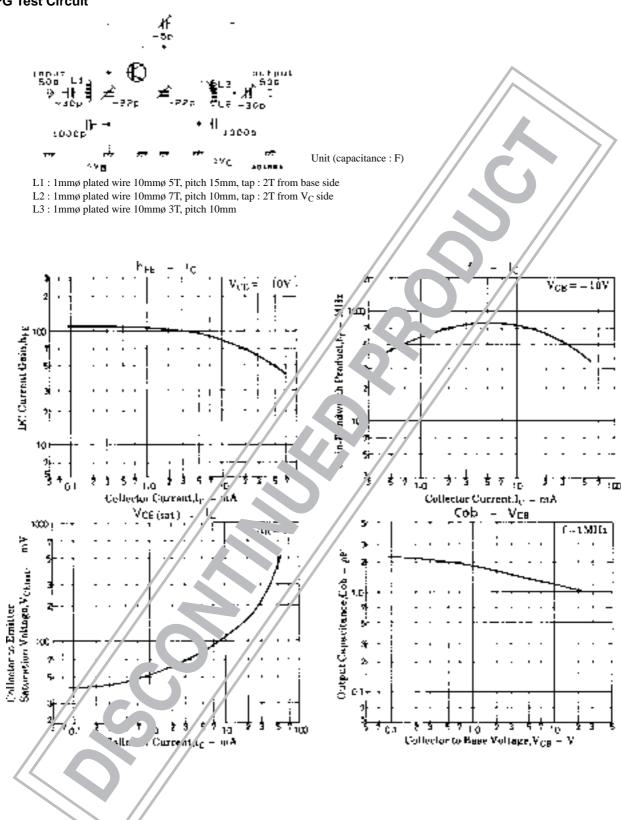
90 1<sub>2</sub> 90 4 180 135 5 270

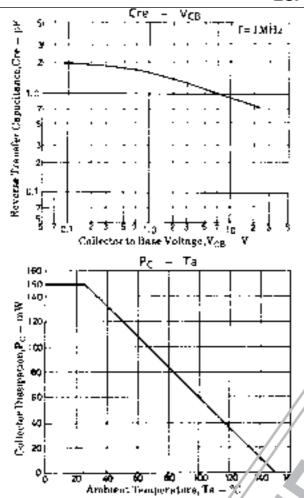
Marking: JS h<sub>FE</sub> rank: 3, 4, 5

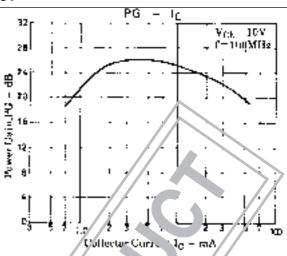
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## **PG Test Circuit**







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